

| PARAMETER  | TEST CONDITION                                     | PART  | SYMBOL            | VALUE              | UNIT             |
|--|--|-------|-------------------|--------------------|------------------|
| INPUT  |  | 1     |                   |                    |                  |
| Reverse voltage  |  |       | $V_{R}$           | 6                  | V                |
| Forward current  |  |       | I <sub>F</sub>    | 20                 | mA               |
| Surge forward current  |  |       | I <sub>FSM</sub>  | 1.5                | А                |
| Power dissipation  | t ≤ 10 μs  |       | P <sub>diss</sub> | 30                 | mW               |
| OUTPUT   |  |       |                   |                    |                  |
| Repetitive peak off-state voltage  |  | BRT11 | $V_{DRM}$         | 400                | V                |
|  |  | BRT12 | $V_{DRM}$         | 600                | V                |
|  |  | BRT13 | $V_{DRM}$         | 800                | V                |
| RMS on-state current   |  |       | I <sub>TRMS</sub> | 300                | mA               |
| Single cycle surge current   | 50 Hz  |       | I <sub>TSM</sub>  | 3                  | Α                |
| Power dissipation  |  |       | P <sub>diss</sub> | 600                | mW               |
| COUPLER  |  |       |                   |                    |                  |
| Maximum power dissipation  |  |       | P <sub>tot</sub>  | 630                | mW               |
| Isolation test voltage<br>(between emitter and detector, climate<br>per DIN 500414, part 2, Nov. 74) (1) |  |       | V <sub>ISO</sub>  | 5300               | $V_{RMS}$        |
| Reference voltage in accordance with VDE 0110 b  |  |       | V <sub>ref</sub>  | 500                | V <sub>RMS</sub> |
| Reference voltage in accordance with VDE 0110 b (insulation group C)                                     |  |       | V <sub>ref</sub>  | 600                | $V_{DC}$         |
| Creepage distance  |  |       |                   | ≥ 7.2              | mm               |
| Clearance distance   |  |       |                   | ≥ 7.2              | mm               |
| Comparative tracking index per<br>DIN IEC 112/VDE 0303 part 1  | group Illa according to<br>DIN VDE 0109            |       | CTI               | ≥ 175              |                  |
| Indiation marietanes   | V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C  |       | R <sub>IO</sub>   | ≥ 10 <sup>12</sup> | Ω                |
| Isolation resistance   | V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C |       | R <sub>IO</sub>   | ≥ 10 <sup>11</sup> | Ω                |
| Storage temperature range  |  |       | T <sub>stg</sub>  | - 40 to + 150      | °C               |
| Ambient temperature range  |  |       | T <sub>amb</sub>  | - 40 to + 100      | °C               |

#### Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

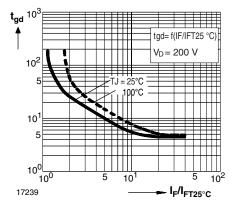
<sup>(1)</sup> Test AC voltage in accordance with DIN 57883, June 1980.

| PARAMETER   | TEST CONDITION  | PART  | SYMBOL                       | MIN.    | TYP.  | MAX.   | UNIT  |
|---|---|-------|------------------------------|---------|-------|--------|-------|
| INPUT   | TEST CONDITION  | FANT  | STWIDOL                      | IVIIIV. | 1115. | IVIAA. | ONIT  |
| Forward voltage   | I <sub>E</sub> = 10 mA  |       | V <sub>F</sub>               |         | 1.1   | 1.35   | V     |
| Reverse current   | V <sub>R</sub> = 6 V  |       | I <sub>R</sub>               |         |       | 10     | μA    |
| Thermal resistance, junction to ambient (1)             |   |       | R <sub>thJA</sub>            |         |       | 750    | °C/W  |
| OUTPUT  |   |       |                              |         | 1     | •      |       |
| Peak off-state voltage                                  | I <sub>D(RMS)</sub> = 100 μA  | BRT11 |                              |         | 400   |        | μΑ    |
|   |   | BRT12 | $V_{DM}$                     |         | 600   |        | μΑ    |
|   |   | BRT13 |                              |         | 800   |        | μΑ    |
| Off-state current                                       | T <sub>C</sub> = 80 °C, V <sub>DRM</sub>                                      |       | I <sub>D</sub>               |         | 0.5   | 100    | μA    |
| On-state voltage  | $I_T = 300 \text{ mA}$  |       | V <sub>T</sub>               |         |       | 2.3    | V     |
| Pulse current   | $t_p \le 5 \ \mu s, \ f = 100 \ Hz, \ dl_{tp}/dt \le 8 \ A/\mu s$             |       | I <sub>tp</sub>              |         |       | 2      | А     |
| Critical rate of rise of off-state voltage              | $V_D = 0.67 \ V_{DRM}, \ T_j = 25 \ ^{\circ}C$                                |       | dV/dt <sub>cr</sub>          | 10      |       |        | kV/μs |
|   | $V_D = 0.67 \ V_{DRM}, \ T_j = 80 \ ^{\circ}C$                                |       | dV/dt <sub>cr</sub>          | 5       |       |        | kV/μs |
| Critical rate of rise of voltage at current commutation | $V_D = 0.67~V_{DRM},~T_j = 25~^{\circ}C,$ dl/dt <sub>crq</sub> $\leq$ 15 A/ms |       | dV/dt <sub>crq</sub>         | 10      |       |        | kV/μs |
|   | $V_D = 0.67 \ V_{DRM}, \ T_j = 80 \ ^{\circ}C,$ $dI/dt_{crq} \le 15 \ A/ms$   |       | dV/dt <sub>crq</sub>         | 5       |       |        | kV/μs |
| Critical rate of rise of on-state at current            |   |       | dl/dt <sub>cr</sub>          | 8       |       |        | A/µs  |
| Holding current   | V <sub>D</sub> = 10 V   |       | I <sub>H</sub>               |         | 80    | 500    | μA    |
| Thermal resistance, junction to ambient                 |   |       | R <sub>thJA</sub>            |         |       | 125    | °C/W  |
| COUPLER   |   |       |                              |         |       |        |       |
| Trigger current   | $V_D = 10 \text{ V}, \text{ F - versions}$                                    |       | I <sub>FT</sub>              |         |       | 1.2    | mA    |
|   | $V_D = 10 \text{ V}, \text{ H} - \text{versions}$                             |       | I <sub>FT</sub>              | 0.4     |       | 2      | mA    |
|   | $V_D = 10 \text{ V}, \text{ M} - \text{versions}$                             |       | I <sub>FT</sub>              | 0.8     |       | 3      | mA    |
| Trigger current temperature gradient                    |   |       | $\Delta I_{FT}/\Delta T_{j}$ |         | 7     | 14     | μΑ/°C |
| Capacitance (input to output)                           | f = 1 MHz, V <sub>R</sub> = 0 V   |       | C <sub>IO</sub>              |         |       | 2      | pF    |

#### **Notes**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.
- (1) Static air, SITAC soldered in PCB or base plate.

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)





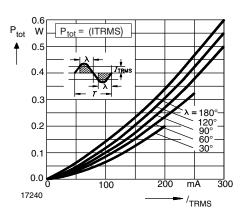


Fig. 2 - Power Dissipation 60 Hz to 60 Hz Line Operation

Rev. 1.6, 02-Dec-11

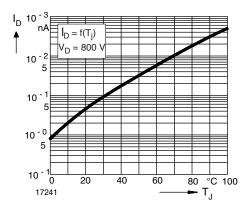


Fig. 3 - Typical Off-State Current

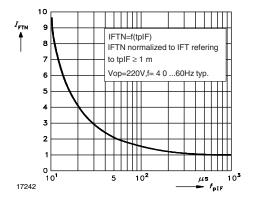


Fig. 4 - Pulse Trigger Current

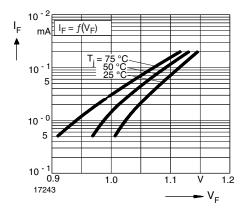


Fig. 5 - Typical Input Characteristics

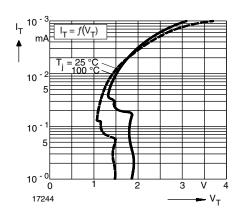


Fig. 6 - Typical Output Characteristics

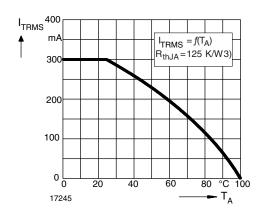


Fig. 7 - Current Reduction

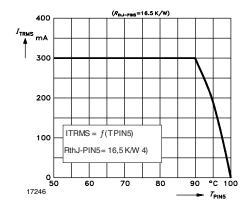
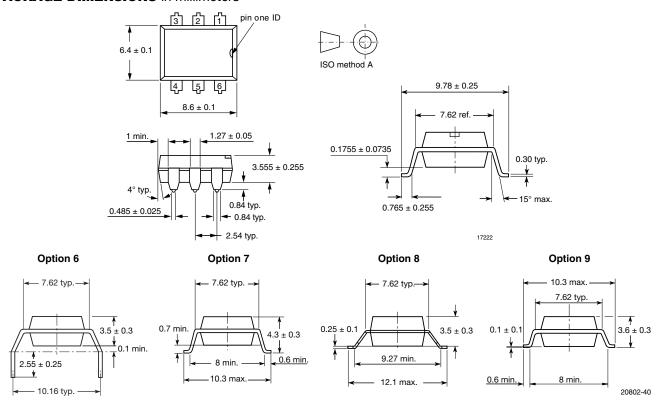


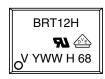
Fig. 8 - Current Reduction



#### **PACKAGE DIMENSIONS** in millimeters



#### **PACKAGE MARKING** (example)



#### Notes

- Only options 1, and 7 are reflected in the package marking.
- The VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.

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